## NSN 5962-01-048-9565

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View Online at https://aerobasegroup.com/nsn/5962-01-048-9565
Body Length:
Between 0.750 inches and 0.808 inches
Body Width:
Between 0.245 inches and 0.294 inches
Body Height:
Between 0.120 inches and 0.179 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set type an/tps-43e
Features Provided:
Hermetically sealed and monolithic and positive outputs and bipolar and programmable and programmed and high speed and 3-state output
and w/buffered output and w/decoded output and w/disable and w/enable and w/storage
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Prom
Memory Capacity:
Unknown
Test Data Document:
97942-635a327 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Unit Of Measure:** 

Shelf Life:

N/a

16 printed circuit

**Terminal Type And Quantity:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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